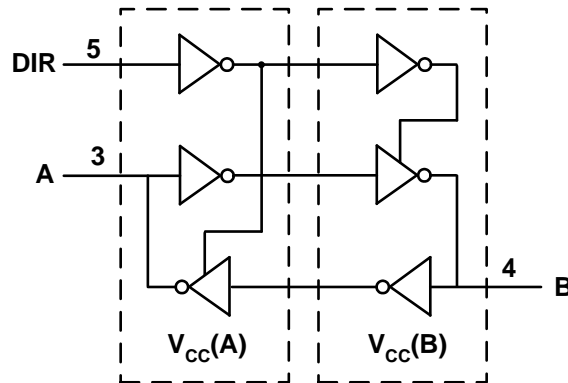


## Pin Descriptions

Pin Name	Pin	Function
VCC(A)	1	Supply for I/O Pin A; Reference for DIR
GND	2	Ground
A	3	Data Input/Output
B	4	Data Input/Output
DIR	5	Direction Control
VCC(B)	6	Supply for I/O Pin B

## Logic Diagram



## Function Tables

Input DIR (Direction Pin)	Operation
L	B Data to A Output
H	A Data to B Output

Inputs			Outputs	
A	B	DIR	A	B
Note 4	L	L	L	Note 4
Note 4	H	L	H	Note 4
L	Note 4	H	Note 4	L
H	Note 4	H	Note 4	H

Note: 4. Pin condition not applicable as defined by DIR.

## Absolute Maximum Ratings (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub> (A), V <sub>CC</sub> (B)	Supply Voltage Range	-0.5 to +6.5	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +6.5	V
V <sub>O</sub>	Voltage Applied to Output in High Impedance or I <sub>OFF</sub> State	-0.5 to +6.5	V
V <sub>O</sub>	Voltage Applied to Output in High or Low State	A Pin	-0.3 to V <sub>CC</sub> (A) +0.5
		B Pin	-0.3 to V <sub>CC</sub> (B) +0.5
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < 0	-50	mA
I <sub>OK</sub>	Output Clamp Current	-50	mA
I <sub>O</sub>	Continuous Output Current	±50	mA
—	Continuous Current Through V <sub>CC</sub> or GND	±100	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

Note: 5. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

**Recommended Operating Conditions** (Note 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter		V <sub>CC</sub> Inputs	V <sub>CC</sub> Outputs	Min	Max	Units
V <sub>CC(A)</sub>	Operating Voltage		—	—	1.65	5.5	V
V <sub>CC(B)</sub>			—	—	1.65	5.5	V
V <sub>IH</sub>	High-Level Input Voltage Pin A or DIR Referenced to V <sub>CC(A)</sub>		V <sub>CC</sub> = 1.65V to 1.95V	—	0.65 X V <sub>CC(A)</sub>	—	V
			V <sub>CC</sub> = 2.3V to 2.7V	—	1.7	—	
			V <sub>CC</sub> = 3V to 3.6V	—	2	—	
			V <sub>CC</sub> = 4.5V to 5.5V	—	0.7 X V <sub>CC(A)</sub>	—	
V <sub>IL</sub>	Low-Level Input Voltage Pin A or DIR Referenced to V <sub>CC(A)</sub>		V <sub>CC</sub> = 1.65V to 1.95V	—	—	0.35 X V <sub>CC(A)</sub>	V
			V <sub>CC</sub> = 2.3V to 2.7V	—	—	0.7	
			V <sub>CC</sub> = 3V to 3.6V	—	—	0.8	
			V <sub>CC</sub> = 4.5V to 5.5V	—	—	0.3 X V <sub>CC(A)</sub>	
V <sub>IH</sub>	High-Level Input Voltage Pin B Referenced to V <sub>CC(B)</sub>		V <sub>CC</sub> = 1.65V to 1.95V	—	0.65 X V <sub>CC(B)</sub>	—	V
			V <sub>CC</sub> = 2.3V to 2.7V	—	1.7	—	
			V <sub>CC</sub> = 3V to 3.6V	—	2	—	
			V <sub>CC</sub> = 4.5V to 5.5V	—	0.7 X V <sub>CC(B)</sub>	—	
V <sub>IL</sub>	Low-Level Input Voltage Pin B Referenced to V <sub>CC(B)</sub>		V <sub>CC</sub> = 1.65V to 1.95V	—	—	0.35 X V <sub>CC(B)</sub>	V
			V <sub>CC</sub> = 2.3V to 2.7V	—	—	0.7	
			V <sub>CC</sub> = 3V to 3.6V	—	—	0.8	
			V <sub>CC</sub> = 4.5V to 5.5V	—	—	0.3 X V <sub>CC(B)</sub>	
V <sub>I</sub>	Input Voltage		—	—	0	5.5	V
V <sub>O</sub>	Output Voltage		—	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current		—	V <sub>CC</sub> = 1.65V to 1.95V	—	-4	mA
			—	V <sub>CC</sub> = 2.3V to 2.7V	—	-8	
			—	V <sub>CC</sub> = 3V to 3.6V	—	-24	
			—	V <sub>CC</sub> = 4.5V to 5.5V	—	-32	
I <sub>OL</sub>	Low-Level Output Current		—	V <sub>CC</sub> = 1.65V to 1.95V	—	4	mA
			—	V <sub>CC</sub> = 2.3V to 2.7V	—	8	
			—	V <sub>CC</sub> = 3V to 3.6V	—	24	
			—	V <sub>CC</sub> = 4.5V to 5.5V	—	32	
Δt/ΔV	Input Transition Rise or Fall Rate	Data Inputs	V <sub>CC</sub> = 1.65V to 1.95V	—	—	20	ns/V
			V <sub>CC</sub> = 2.3V to 2.7V	—	—	20	
			V <sub>CC</sub> = 3V to 3.6V	—	—	10	
			V <sub>CC</sub> = 4.5V to 5.5V	—	—	5	
		Control Inputs		V <sub>CC</sub> = 1.65V to 5.5V	—	—	
T <sub>A</sub>	Operating Free-Air Temperature		—	—	-40	+125	°C

Note: 6. Unused inputs should be held at V<sub>CC</sub> or Ground.

**Electrical Characteristics** (@T<sub>A</sub> = +40°C to +85°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions		V <sub>CC</sub> (A)	V <sub>CC</sub> (B)	T <sub>A</sub> = +25°C			T <sub>A</sub> = -40°C to +85°C		Unit
						Min	Typ	Max	Min	Max	
V <sub>OH</sub>	High Level Output Voltage	I <sub>OH</sub> = -100μA		1.65V to 5.5V	1.65V to 5.5V	—	—	—	V <sub>CC</sub> - 0.1	—	V
		I <sub>OH</sub> = -4mA		1.65V	1.65V	—	—	—	1.2	—	
		I <sub>OH</sub> = -8mA		2.3V	2.3V	—	—	—	1.9	—	
		I <sub>OH</sub> = -24mA		3V	3V	—	—	—	2.4	—	
		I <sub>OH</sub> = -32mA		4.5V	4.5V	—	—	—	3.8	—	
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 100μA		1.65V to 5.5V	1.65V to 5.5V	—	—	—	—	0.1	V
		I <sub>OL</sub> = 4mA		1.65V	1.65V	—	—	—	—	0.45	
		I <sub>OL</sub> = 8mA		2.3V	2.3V	—	—	—	—	0.3	
		I <sub>OL</sub> = 24mA		3V	3V	—	—	—	—	0.55	
		I <sub>OL</sub> = 32mA		4.5V	4.5V	—	—	—	—	0.55	
I <sub>I</sub>	Input Current	DIR	V <sub>I</sub> = V <sub>CC</sub> (A) or GND	0 to 5.5V	0 to 5.5V	—	—	±1	—	±2	μA
I <sub>OFF</sub>	Power Down Leakage Current	A Pin	V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5V	0	0V to 5.5V	—	—	±1	—	±2	μA
		B Pin		0 to 5.5V	0	—	—	±1	—	±2	
I <sub>OZ</sub>	3-State Leakage Current	A Pin	V <sub>O</sub> = V <sub>CC</sub> (A)	1.65V to 5.5V	1.65V to 5.5V	—	—	±1	—	±2	μA
		B Pin	V <sub>O</sub> = V <sub>CC</sub> (B)	1.65V to 5.5V	1.65V to 5.5V	—	—	±1	—	±2	
I <sub>CCA</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	—	—	—	3	μA
				5.5V	0	—	—	—	—	2	
				0	5.5V	—	—	—	—	-2	
I <sub>CCB</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	—	—	—	3	μA
				0V	5.5V	—	—	—	—	2	
				5.5V	0V	—	—	—	—	-2	
I <sub>CCA</sub> + I <sub>CCB</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	—	—	—	4	μA
ΔI <sub>CCA</sub>	Additional Supply Current	A Pin	A = V <sub>CC</sub> (A) -0.6V DIR = V <sub>CC</sub> (A) B = Open	3V to 5.5V	3V to 5.5V	—	—	—	—	50	μA
		DIR	DIR = V <sub>CC</sub> (A) -0.6V A = V <sub>CC</sub> (A) or GND B = Open							50	
ΔI <sub>CCB</sub>	Additional Supply Current	B Pin	B = V <sub>CC</sub> (B) -0.6V DIR = GND A = Open	3V to 5.5V	3V to 5.5V	—	—	—	—	50	μA
C <sub>I</sub>	Input Capacitance	DIR	V <sub>I</sub> = V <sub>CC</sub> (A) or GND	3.3V	3.3V	—	2.5	—	—	—	pF
C <sub>IO</sub>	Input/Output Capacitance	A or B Pin	V <sub>I</sub> = V <sub>CC</sub> (A)/(B) or GND	3.3V	3.3V	—	6.0	—	—	—	pF

**Electrical Characteristics** (@T<sub>A</sub> = +40°C to +125°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions		V <sub>CC</sub> (A)	V <sub>CC</sub> (B)	T <sub>A</sub> = -40°C to +125°C		Unit
						Min	Max	
V <sub>OH</sub>	High Level Output Voltage	I <sub>OH</sub> = -100μA		1.65V to 5.5V	1.65V to 5.5V	V <sub>CC</sub> – 0.1	—	V
		I <sub>OH</sub> = -4mA		1.65V	1.65V	1.2	—	
		I <sub>OH</sub> = -8mA		2.3V	2.3V	1.9	—	
		I <sub>OH</sub> = -24mA		3V	3V	2.4	—	
		I <sub>OH</sub> = -32mA		4.5V	4.5V	3.8	—	
V <sub>OL</sub>	High-Level Input Voltage	I <sub>OL</sub> = 100μA		1.65V to 5.5V	1.65V to 5.5V	—	0.1	V
		I <sub>OL</sub> = 4mA		1.65V	1.65V	—	0.45	
		I <sub>OL</sub> = 8mA		2.3V	2.3V	—	0.3	
		I <sub>OL</sub> = 24mA		3V	3V	—	0.55	
		I <sub>OL</sub> = 32mA		4.5V	4.5V	—	0.55	
I <sub>I</sub>	Input Current	DIR	V <sub>I</sub> = V <sub>CC</sub> (A) or GND	0 to 5.5V	0 to 5.5V	—	± 2	μA
I <sub>OFF</sub>	Power Down Leakage Current	A Pin	V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5V	0	1.65V to 5.5V	—	± 2	μA
		B Pin		1.65V to 5.5V	0V	—	± 2	
I <sub>OZ</sub>	3-State Leakage Current	B Pin V <sub>O</sub> =V <sub>CC</sub> (B) DIR = 0 V	V <sub>I</sub> = 0 to 5.5V	1.65V to 5.5V	1.65V to 5.5V	—	± 2	μA
		A Pin V <sub>O</sub> = V <sub>CC</sub> (A) DIR= V <sub>CC</sub> (A)		1.65V to 5.5V	1.65V to 5.5V	—	± 2	
I <sub>CCA</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	3	μA
				5.5V	0	—	2	
				0	5.5V	—	-2	
I <sub>CCB</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	3	μA
				5.5V	0	—	2	
				0	5.5V	—	-2	
I <sub>CCA</sub> + I <sub>CCB</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	1.65V to 5.5V	—	4	μA
ΔI <sub>CCA</sub>	Additional Supply Current	A Pin	A = V <sub>CC</sub> (A) -0.6V DIR = V <sub>CC</sub> (A) B = Open	3V to 5.5V	3V to 5.5V	—	50	μA
		DIR	DIR= V <sub>CC</sub> (A) -0.6V A= V <sub>CC</sub> (A) or GND B = Open				50	
ΔI <sub>CCB</sub>	Additional Supply Current	B Pin	B = V <sub>CC</sub> (B) -0.6V DIR = GND A = Open	3V to 5.5V	3V to 5.5V	—	50	μA

**Package Characteristics** ( $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$ , unless otherwise specified.)

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
$\Theta_{JA}$	Thermal Resistance Junction-to-Ambient	SOT26	Note 7	—	166	—	$^\circ C/W$
		SOT363		—	371	—	
		SOT563		—	290	—	
		DFN1410		—	430	—	
		DFN1409		—	450	—	
		DFN1010		—	510	—	
$\Theta_{JC}$	Thermal Resistance Junction-to-Case	SOT26	Note 7	—	46	—	$^\circ C/W$
		SOT363		—	143	—	
		SOT563		—	96	—	
		DFN1410		—	190	—	
		DFN1409		—	200	—	
		DFN1010		—	250	—	

Note: 7. Test condition for SOT26, SOT363, DFN1410, DFN1409 and DFN1010: Device mounted on FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

**Switching Characteristics** ( $V_{CC}(A) = 1.8V \pm 0.15V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , see Figure 1)

Parameter	From (Input)	To (Output)	$V_{CC}(B) = 1.8V \pm 0.15V$		$V_{CC}(B) = 2.5V \pm 0.2V$		$V_{CC}(B) = 3.3V \pm 0.3V$		$V_{CC}(B) = 5V \pm 0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pLH}$	A	B	3	17.7	2.2	10.3	1.7	8.3	1.4	7.5	ns
$t_{pHL}$			2.8	14.3	2.2	8.5	1.8	8.1	1.7	7.5	
$t_{pLH}$	B	A	3	17.7	2.3	16	2.1	15.5	1.9	15.1	ns
$t_{pHL}$			2.8	14.3	2.1	12.9	2	12.6	1.8	12.2	
$t_{pHZ}$	DIR	A	5.2	19.4	4.8	18.5	4.7	18.4	5.1	17.1	ns
$t_{pLZ}$			2.3	10.5	2.1	10.5	2.4	10.7	3.1	10.9	
$t_{pHZ}$	DIR	B	6.4	21.9	4.9	11.5	4.6	10.3	2.8	8.2	ns
$t_{pLZ}$			4.2	17	3.7	9.6	3.3	8.8	2.4	8.0	
$t_{pZH}$	DIR	A	—	33.7	—	25.2	—	23.9	—	21.5	ns
$t_{pZL}$			—	36.2	—	24.4	—	22.9	—	20.4	
$t_{pZH}$	DIR	B	—	28.2	—	20.8	—	19	—	18.1	ns
$t_{pZL}$			—	33.7	—	27	—	25.5	—	24.1	

**Switching Characteristics** (continued) ( $V_{CC}(A) = 2.5V \pm 0.2V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , see Figure 1)

Parameter	From (Input)	To (Output)	$V_{CC}(B) = 1.8V \pm 0.15V$		$V_{CC}(B) = 2.5V \pm 0.2V$		$V_{CC}(B) = 3.3V \pm 0.3V$		$V_{CC}(B) = 5V \pm 0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pLH}$	A	B	2.3	16	1.5	8.5	1.3	6.4	1.1	5.1	ns
$t_{pHL}$			2.1	12.9	1.4	7.5	1.3	5.4	0.9	4.6	
$t_{pLH}$	B	A	2.2	10.3	1.5	8.5	1.4	8	1	7.5	ns
$t_{pHL}$			2.2	8.5	1.4	7.5	1.3	7	0.9	6.2	
$t_{pHZ}$	DIR	A	3	8.1	3.1	8.1	2.8	8.1	3.2	8.1	ns
$t_{pLZ}$			1.3	5.9	1.3	5.9	1.3	5.9	1	5.8	
$t_{pHZ}$	DIR	B	5.5	23.7	3.6	11.4	3.5	10.2	2.4	7.1	ns
$t_{pLZ}$			3.9	18.9	3.2	9.6	2.8	8.4	1.8	5.3	
$t_{pZH}$	DIR	A	—	29.2	—	18.1	—	16.4	—	12.8	ns
$t_{pZL}$			—	32.2	—	18.9	—	17.2	—	13.3	
$t_{pZH}$	DIR	B	—	21.9	—	14.4	—	12.3	—	10.9	ns

**Switching Characteristics** (continued) ( $V_{CC}(A) = 3.3V \pm 0.3V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , see Figure 1)

Parameter	From (Input)	To (Output)	$V_{CC}(B) = 1.8V \pm 0.15V$		$V_{CC}(B) = 2.5V \pm 0.2V$		$V_{CC}(B) = 3.3V \pm 0.3V$		$V_{CC}(B) = 5V \pm 0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pLH}$	A	B	2.1	15.5	1.4	8	0.7	5.8	0.7	4.4	ns
$t_{pHL}$			2	12.6	1.3	7	0.8	5	0.7	4	
$t_{pLH}$	B	A	1.7	8.3	1.3	6.4	0.7	5.8	0.6	5.4	ns
$t_{pHL}$			1.8	7.1	1.3	5.4	0.8	5	0.7	4.5	
$t_{pHZ}$	DIR	A	2.9	7.3	3	7.3	2.8	7.3	3.4	7.3	ns
$t_{pLZ}$			1.8	5.6	1.6	5.6	2.2	5.7	2.2	5.7	
$t_{pHZ}$	DIR	B	4.0	20.5	3.5	10.1	2.9	8.8	2.4	6.8	ns
$t_{pLZ}$			3.3	14.5	2.9	7.8	2.4	7.1	1.7	4.9	
$t_{pZH}$	DIR	A	—	22.8	—	14.2	—	12.9	—	10.3	ns
$t_{pZL}$			—	27.6	—	15.5	—	13.8	—	11.3	
$t_{pZH}$	DIR	B	—	21.1	—	13.6	—	11.5	—	10.1	ns
$t_{pZL}$			—	19.9	—	14.3	—	12.3	—	11.3	

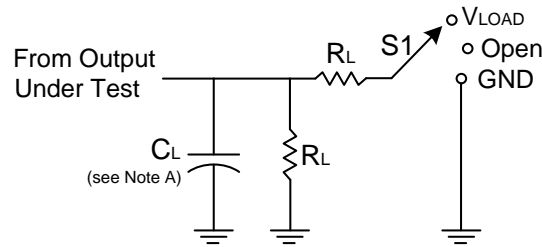
**Switching Characteristics** (continued) ( $V_{CC}(A) = 5V \pm 0.5V$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , see Figure 1)

Parameter	From (Input)	To (Output)	$V_{CC}(B) = 1.8V \pm 0.15V$		$V_{CC}(B) = 2.5V \pm 0.2V$		$V_{CC}(B) = 3.3V \pm 0.3V$		$V_{CC}(B) = 5V \pm 0.5V$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pLH}$	A	B	1.9	15.1	1	7.5	0.6	5.4	0.5	3.9	ns
$t_{pHL}$			1.8	12.2	0.9	6.2	0.7	4.5	0.5	3.5	
$t_{pLH}$	B	A	1.4	8.5	1	5.1	0.7	4.4	0.5	3.9	ns
$t_{pHL}$			1.7	8.5	0.9	4.6	0.7	4	0.5	3.5	
$t_{pHZ}$	DIR	A	2.1	5.4	2.2	5.4	2.2	5.5	2.2	5.4	ns
$t_{pLZ}$			0.9	3.8	1	3.8	1	3.7	0.9	3.7	
$t_{pHZ}$	DIR	B	4.8	20.2	2.5	9.8	1	8.5	2.2	6.5	ns
$t_{pLZ}$			4.2	14.8	2.5	7.4	2.5	7	1.6	4.5	
$t_{pZH}$	DIR	A	—	22	—	12.5	—	11.4	—	8.4	ns
$t_{pZL}$			—	27.2	—	14.4	—	12.5	—	10	
$t_{pZH}$	DIR	B	—	18.9	—	11.3	—	9.1	—	7.6	ns

**Operating Characteristics** ( $T_A = +25^\circ C$ , unless otherwise specified.)

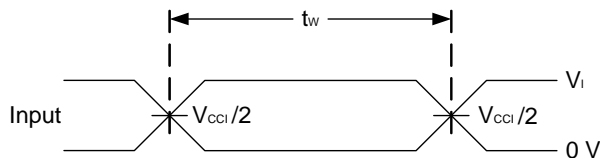
Parameter Power Dissipation Capacitance		Test Conditions	$V_{CC}(A) =$ $V_{CC}(B) = 1.8V$	$V_{CC}(A) =$ $V_{CC}(B) = 2.5V$	$V_{CC}(A) =$ $V_{CC}(B) = 3.3V$	$V_{CC}(A) =$ $V_{CC}(B) = 5V$	Unit
			Typ	Typ	Typ	Typ	
$C_{pd}(A)$	A- Input, B- Output	$C_L = 0\text{ pF}$	3	4	4	4	pF
	B- Input, A- Output	$f = 10\text{ MHz}$ $t_r = t_f = 1\text{ ns}$	18	19	20	21	
$C_{pd}(B)$	A- Input, B- Output	$C_L = 0\text{ pF}$	18	19	20	21	pF
	B- Input, A- Output	$f = 10\text{ MHz}$ $t_r = t_f = 1\text{ ns}$	3	4	4	4	

## Parameter Measurement Information

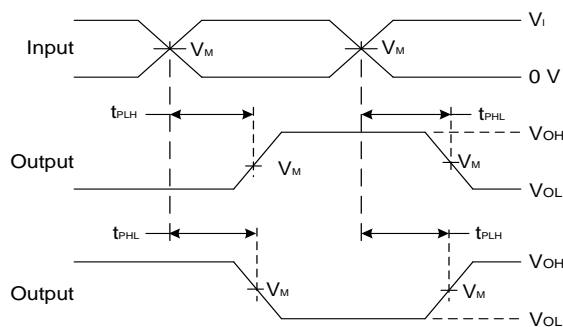


TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

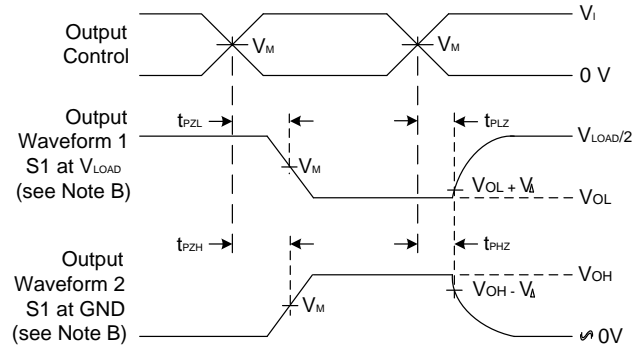
$V_{CC}$	Inputs		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
$1.8V \pm 0.15V$	$V_{CCI}$	$\leq 2ns$	$V_{CCO}/2$	$2 \times V_{CCO}$	15pF	2K $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CCO}/2$	$2 \times V_{CCO}$	15pF	2K $\Omega$	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	$V_{CCO}/2$	$2 \times V_{CCO}$	15pF	2K $\Omega$	0.3V
$5V \pm 0.5V$	$V_{CC}$	$\leq 2.5ns$	$V_{CCO}/2$	$2 \times V_{CCO}$	15pF	2K $\Omega$	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times  
Inverting and Non Inverting Outputs

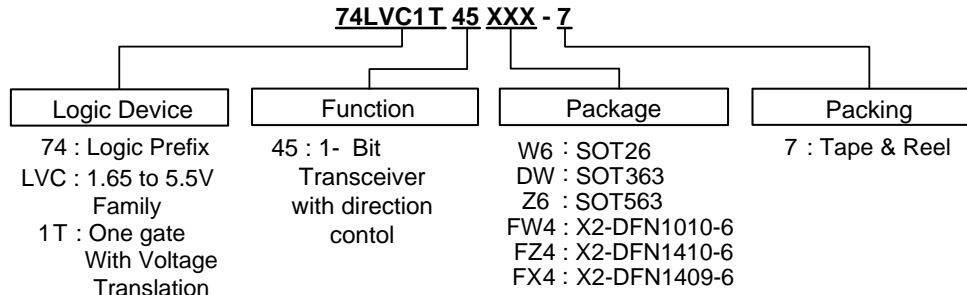


Voltage Waveform Enable and Disable Times  
Low and High Level Enabling

Figure 1 Load Circuit and Voltage Waveforms

- Notes:
- Includes test lead and test apparatus capacitance.
  - Waveform 1 is for an output with input set up as a low and device coming out or into 3-state via DIR control.
  - Waveform 2 is for an output with input set up as a high and device coming out or into 3-state via DIR control.
  - All pulses are supplied at pulse repetition rate  $\leq 10$  MHz.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .
  - $V_{CCI}$  is the  $V_{CC}$  associated with the input.
  - $V_{CCO}$  is the  $V_{CC}$  associated with the output.

## Ordering Information

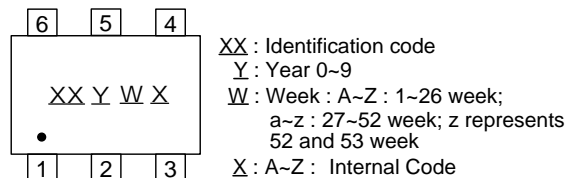


Part Number	Package Code	Packaging	7" Tape and Reel (Note 7)	
			Quantity	Part Number Suffix
74LVC1T45W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC1T45DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC1T45Z6-7	Z6	SOT563	4000/Tape & Reel	-7
74LVC1T45FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74LVC1T45FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7
74LVC1T45FX4-7	FX4	X2-DFN1409-6	5000/Tape & Reel	-7

Note: 16. The taping orientation is located on our website at <http://www.diodes.com/package-outlines.html>.

## Marking Information

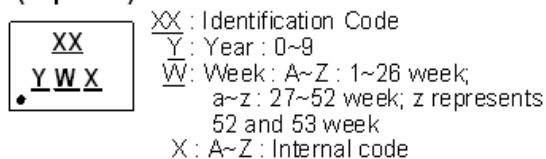
### (1) SOT363, SOT563



Part Number	Package	Identification Code
74LVC1T45W6	SOT26	TT
74LVC1T45DW	SOT363	TR
74LVC1T45Z6	SOT563	TS

### (2) X2-DFN1010-6, X2-DFN1410-6, and X2-DFN1409-6

#### (Top View)

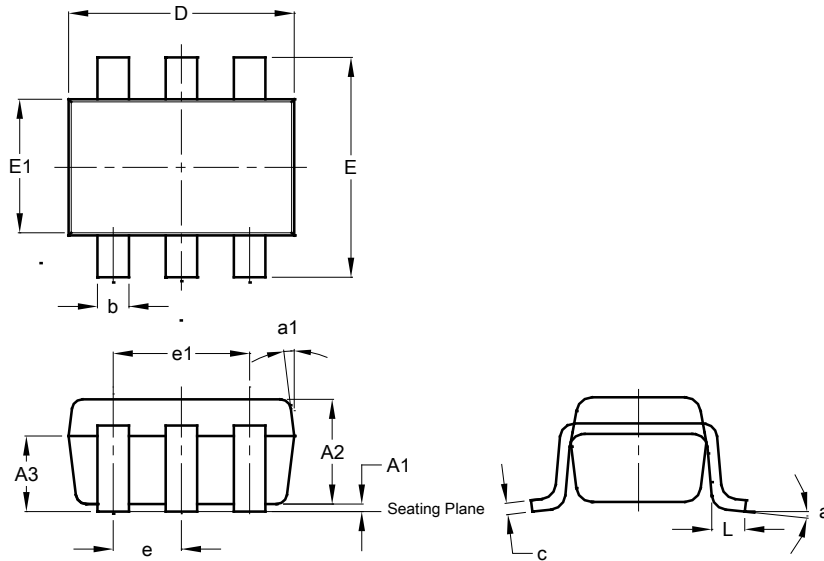


Part Number	Package	Identification Code
74LVC1T45FW4	X2-DFN1010-6	TR
74LVC1T45FX4	X2-DFN1409-6	TT
74LVC1T45FZ4	X2-DFN1410-6	TS

## Package Outline Dimensions (All dimensions in mm.)

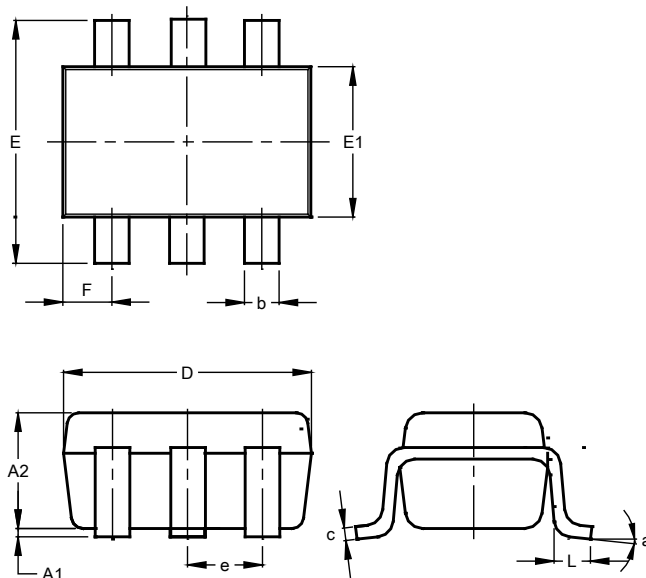
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SOT26



SOT26 (SC74R)			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	—	—	0.95
e1	—	—	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	—	—	8°
a1	—	—	7°
All Dimensions in mm			

### (2) Package Type: SOT363

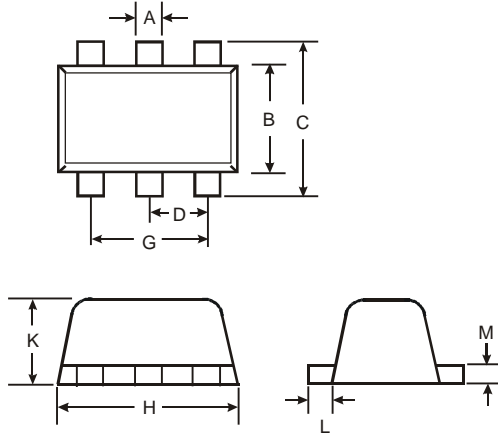


SOT363			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	—
All Dimensions in mm			

## Package Outline Dimensions (All dimensions in mm.)

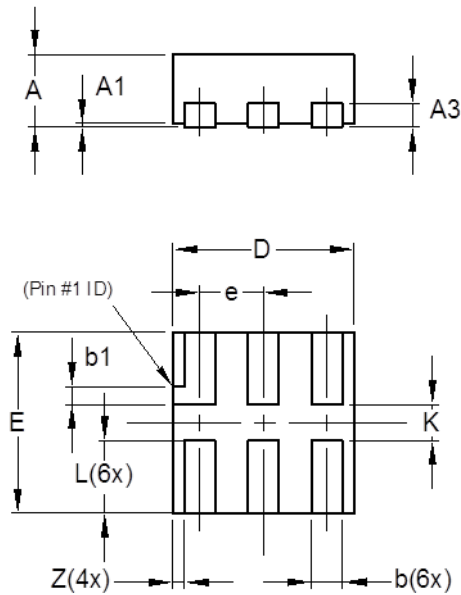
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (3) Package Type: SOT563



SOT563			
Dim	Min	Max	Typ
A	0.15	0.30	0.20
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	—	—	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.55	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

### (4) Package Type X2-DFN1010-6

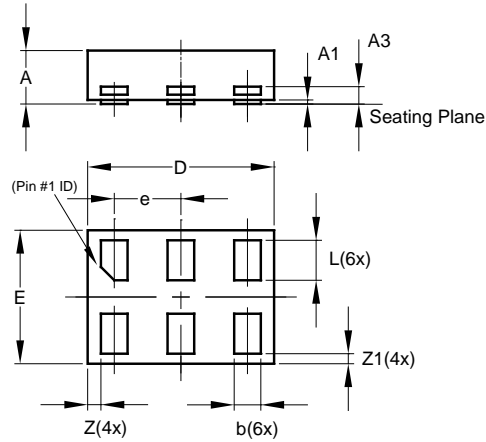


X2-DFN1010-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
E	0.95	1.05	1.00
e	—	—	0.35
L	0.35	0.45	0.40
K	0.15	—	—
Z	—	—	0.065
All Dimensions in mm			

## Package Outline Dimensions (All dimensions in mm.)

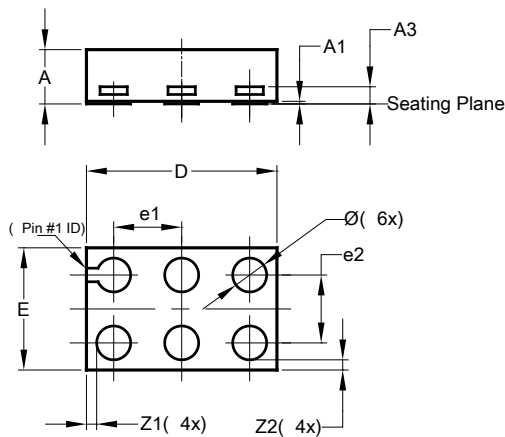
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (5) Package Type: X2-DFN1410-6



X2-DFN1410-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
e	—	—	0.50
L	0.25	0.35	0.30
Z	—	—	0.10
Z1	0.045	0.105	0.075
All Dimensions in mm			

### (6) Package Type: X2-DFN1409-6

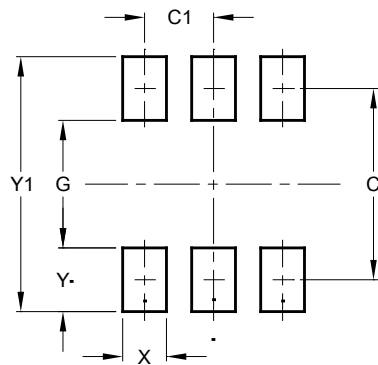


X2-DFN1409-6			
Dim	Min	Max	Typ
A	-	0.40	0.39
A1	0	0.05	0.02
A3	-	-	0.13
Ø	0.20	0.30	0.25
D	1.35	1.45	1.40
E	0.85	0.95	0.90
e1	-	-	0.50
e2	-	-	0.50
Z1	-	-	0.075
Z2	-	-	0.075
All Dimensions in mm			

## Suggested Pad Layout

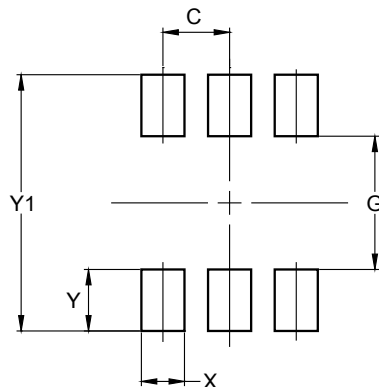
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SOT26



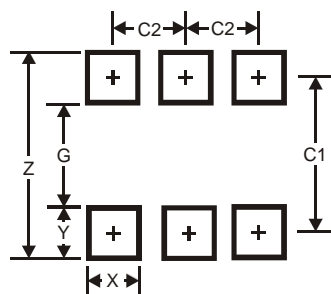
Dimensions	Value (in mm)
<b>C</b>	2.40
<b>C1</b>	0.95
<b>G</b>	1.60
<b>X</b>	0.55
<b>Y</b>	0.80
<b>Y1</b>	3.20

### (2) Package Type: SOT363



Dimensions	Value (in mm)
<b>C</b>	0.650
<b>G</b>	1.300
<b>X</b>	0.420
<b>Y</b>	0.600
<b>Y1</b>	2.500

### (3) Package Type: SOT563

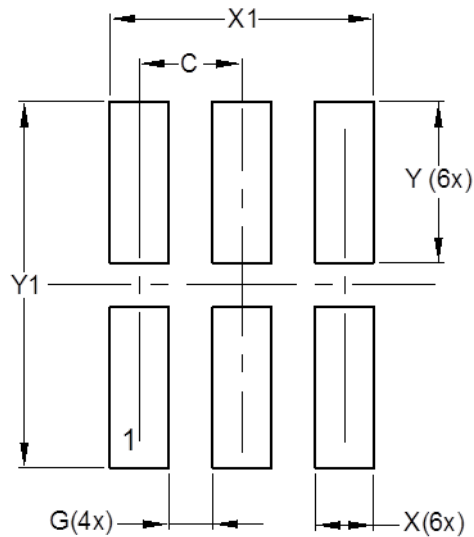


Dimensions	SOT563
<b>Z</b>	2.2
<b>G</b>	1.2
<b>X</b>	0.375
<b>Y</b>	0.5
<b>C1</b>	1.7
<b>C2</b>	0.5

## Suggested Pad Layout

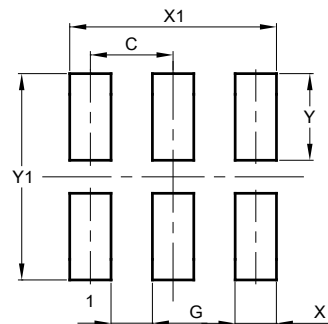
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (4) Package Type X2-DFN1010-6



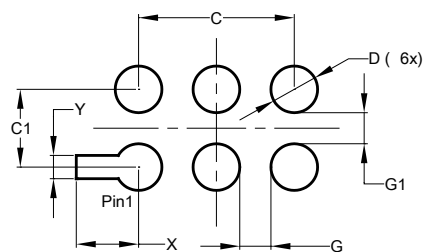
Dimensions	Value (in mm)
C	0.350
G	0.150
X	0.200
X1	0.900
Y	0.550
Y1	1.250

### (5) Package Type: X2-DFN1410-6



Dimension s	Value (in mm)
C	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

### (6) Package Type: X2-DFN1409-6



Dimensions	Value (in mm)
C	1.000
C1	0.500
D	0.300
G	0.200
G1	0.200
X	0.400
Y	0.150

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